



3.3V CMOS 20-BIT BUS-INTERFACE D-TYPE LATCH WITH 3-STATE OUT- PUTS AND BUS-HOLD

IDT74ALVCH16841

FEATURES:

- 0.5 MICRON CMOS Technology
- Typical $t_{sk(o)}$ (Output Skew) < 250ps
- ESD > 2000V per MIL-STD-883, Method 3015; > 200V using machine model ($C = 200\text{pF}$, $R = 0$)
- $V_{CC} = 3.3V \pm 0.3V$, Normal Range
- $V_{CC} = 2.7V$ to $3.6V$, Extended Range
- $V_{CC} = 2.5V \pm 0.2V$
- CMOS power levels ($0.4\mu\text{W}$ typ. static)
- Rail-to-Rail output swing for increased noise margin
- Available in SSOP, TSSOP, and TVSOP packages

DRIVE FEATURES:

- High Output Drivers: $\pm 24\text{mA}$
- Suitable for heavy loads

APPLICATIONS:

- 3.3V high speed systems
- 3.3V and lower voltage computing systems

DESCRIPTION:

This 20-bit interface D-type latch is built using advanced dual metal CMOS technology. The ALVCH16841 features 3-state outputs designed specifically for driving highly capacitive relatively low-impedance loads. This device is particularly suitable for implementing buffer registers, unidirectional bus drivers, and working registers.

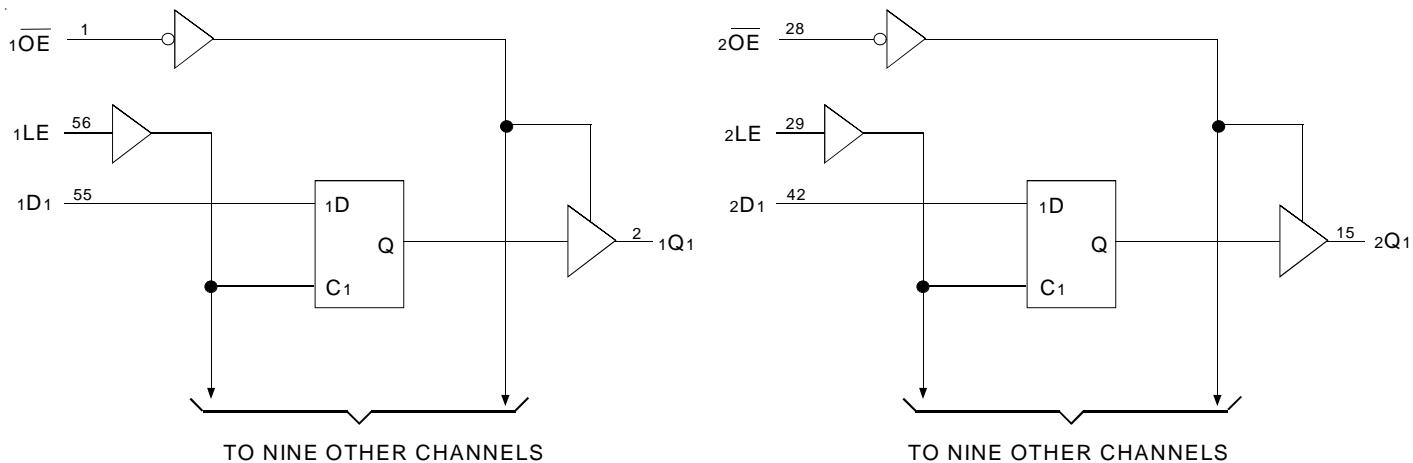
The ALVCH16841 can be used as two 10-bit latches or one 20-bit latch. The 20 latches are transparent D-type latches. The device has noninverting data (D) inputs and provides true data at its outputs. While the latch-enable (1LE or 2LE) input is high, the Q outputs of the corresponding 10-bit latch follow the D inputs. When LE is taken low, the Q outputs are latched at the levels set up at the D inputs.

A buffered output-enable ($1\overline{OE}$ or $2\overline{OE}$) input can be used to place the outputs of the corresponding 10-bit latch in either a normal logic state (high or low logic levels) or a high-impedance state. In the high-impedance state, the outputs neither load nor drive the bus lines significantly. \overline{OE} does not affect the internal operation of the latches. Old data can be retained or new data can be entered while the outputs are in the high-impedance state.

The ALVCH16841 has been designed with a $\pm 24\text{mA}$ output driver. This driver is capable of driving a moderate to heavy load while maintaining speed performance.

The ALVCH16841 has "bus-hold" which retains the inputs' last state whenever the input bus goes to a high impedance. This prevents floating inputs and eliminates the need for pull-up/down resistors.

FUNCTIONAL BLOCK DIAGRAM



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INDUSTRIAL TEMPERATURE RANGE

MARCH 1999

PIN CONFIGURATION

1	56	1LE
2	55	1D1
3	54	1D2
GND	4	GND
1Q3	5	1D3
1Q4	6	1D4
VCC	7	VCC
1Q5	8	1D5
1Q6	9	1D6
1Q7	10	1D7
GND	11	GND
1Q8	12	1D8
1Q9	13	1D9
1Q10	14	1D10
2Q1	15	2D1
2Q2	16	2D2
2Q3	17	2D3
GND	18	GND
2Q4	19	2D4
2Q5	20	2D5
2Q6	21	2D6
Vcc	22	Vcc
2Q7	23	2D7
2Q8	24	2D8
GND	25	GND
2Q9	26	2D9
2Q10	27	2D10
2OE	28	2LE

SSOP/ TSSOP/ TVSOP
TOP VIEWABSOLUTE MAXIMUM RATINGS⁽¹⁾

Symbol	Description	Max	Unit
VTERM ⁽²⁾	Terminal Voltage with Respect to GND	-0.5 to +4.6	V
VTERM ⁽³⁾	Terminal Voltage with Respect to GND	-0.5 to Vcc+0.5	V
TSTG	Storage Temperature	-65 to +150	°C
IOUT	DC Output Current	-50 to +50	mA
Iik	Continuous Clamp Current, Vi < 0 or Vi > Vcc	±50	mA
lok	Continuous Clamp Current, Vo < 0	-50	mA
Icc	Continuous Current through each Vcc or GND	±100	mA
Iss			

NOTES:

- Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.
- Vcc terminals.
- All terminals except Vcc.

CAPACITANCE ($T_A = +25^\circ\text{C}$, $F = 1.0\text{MHz}$)

Symbol	Parameter ⁽¹⁾	Conditions	Typ.	Max.	Unit
Cin	Input Capacitance	$V_{IN} = 0V$	5	7	pF
Cout	Output Capacitance	$V_{OUT} = 0V$	7	9	pF
Cout	I/O Port Capacitance	$V_{IN} = 0V$	7	9	pF

NOTE:

- As applicable to the device type.

PIN DESCRIPTION

Pin Names	Description
xDx	Data Inputs ⁽¹⁾
xLE	Latch Enable Inputs (Active HIGH)
xOE	Output Enable Inputs (Active LOW)
xQx	3-State Outputs

NOTE:

- These pins have "Bus-Hold". All other pins are standard inputs, outputs, or I/Os.

FUNCTION TABLE (EACH 10-BIT LATCH)⁽¹⁾

Inputs			Output
xDx	xLE	xOE	xQx
H	H	L	H
L	H	L	L
X	L	L	Q ²
X	X	H	Z

NOTES:

- H = HIGH Voltage Level
L = LOW Voltage Level
X = Don't Care
Z = High-Impedance
- Output level before the indicated steady-state input conditions were established.

DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified:

Operating Condition: TA = -40°C to +85°C

Symbol	Parameter	Test Conditions		Min.	Typ. ⁽¹⁾	Max.	Unit
VIH	Input HIGH Voltage Level	VCC = 2.3V to 2.7V		1.7	—	—	V
		VCC = 2.7V to 3.6V		2	—	—	
VIL	Input LOW Voltage Level	VCC = 2.3V to 2.7V		—	—	0.7	V
		VCC = 2.7V to 3.6V		—	—	0.8	
I _{IH}	Input HIGH Current	VCC = 3.6V	VI = VCC	—	—	±5	µA
I _{IL}	Input LOW Current	VCC = 3.6V	VI = GND	—	—	±5	µA
I _{OZH}	High Impedance Output Current (3-State Output pins)	VCC = 3.6V	VO = VCC	—	—	±10	µA
			VO = GND	—	—	±10	
V _{IK}	Clamp Diode Voltage	VCC = 2.3V, I _{IN} = -18mA		—	-0.7	-1.2	V
V _H	Input Hysteresis	VCC = 3.3V		—	100	—	mV
I _{CCL} I _{CCH} I _{CZZ}	Quiescent Power Supply Current	VCC = 3.6V VIN = GND or VCC		—	0.1	40	µA
ΔI _{CC}	Quiescent Power Supply Current Variation	One input at VCC - 0.6V, other inputs at VCC or GND		—	—	750	µA

NOTE:

1. Typical values are at VCC = 3.3V, +25°C ambient.

BUS-HOLD CHARACTERISTICS

Symbol	Parameter ⁽¹⁾	Test Conditions		Min.	Typ. ⁽²⁾	Max.	Unit
I _{BHH} I _{BHL}	Bus-Hold Input Sustain Current	VCC = 3V	VI = 2V	-75	—	—	µA
			VI = 0.8V	75	—	—	
I _{BHH} I _{BHL}	Bus-Hold Input Sustain Current	VCC = 2.3V	VI = 1.7V	-45	—	—	µA
			VI = 0.7V	45	—	—	
I _{BHHO} I _{BHLO}	Bus-Hold Input Overdrive Current	VCC = 3.6V	VI = 0 to 3.6V	—	—	±500	µA

NOTES:

1. Pins with Bus-Hold are identified in the pin description.

2. Typical values are at VCC = 3.3V, +25°C ambient.

OUTPUT DRIVE CHARACTERISTICS

Symbol	Parameter	Test Conditions ⁽¹⁾		Min.	Max.	Unit
VOH	Output HIGH Voltage	VCC = 2.3V to 3.6V	I _{OH} = - 0.1mA	VCC - 0.2	—	V
		VCC = 2.3V	I _{OH} = - 6mA	2	—	
		VCC = 2.3V	I _{OH} = - 12mA	1.7	—	
		VCC = 2.7V		2.2	—	
		VCC = 3V	I _{OH} = - 24mA	2.4	—	
		VCC = 3V		2	—	
VOL	Output LOW Voltage	VCC = 2.3V to 3.6V	I _{OL} = 0.1mA	—	0.2	V
		VCC = 2.3V	I _{OL} = 6mA	—	0.4	
			I _{OL} = 12mA	—	0.7	
		VCC = 2.7V	I _{OL} = 12mA	—	0.4	
		VCC = 3V	I _{OL} = 24mA	—	0.55	

NOTE:

1. V_{IH} and V_{IL} must be within the min. or max. range shown in the DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE table for the appropriate V_{cc} range.
TA = - 40°C to + 85°C.

OPERATING CHARACTERISTICS, TA = 25°C

Symbol	Parameter	Test Conditions	V _{cc} = 2.5V ± 0.2V	V _{cc} = 3.3V ± 0.3V	Unit
			Typical	Typical	
CPD	Power Dissipation Capacitance Outputs enabled	C _L = 0pF, f = 10Mhz	12	20	pF
	Power Dissipation Capacitance Outputs disabled		1	3	

SWITCHING CHARACTERISTICS⁽¹⁾

Symbol	Parameter	V _{cc} = 2.5V ± 0.2V		V _{cc} = 2.7V		V _{cc} = 3.3V ± 0.3V		Unit
		Min.	Max.	Min.	Max.	Min.	Max.	
t _{PLH}	Propagation Delay x _{Dx} to x _{Qx}	1	5	—	4.7	1.2	3.9	ns
t _{PHL}	Propagation Delay x _{LE} to x _{Qx}	1	5.6	—	5.1	1	4.3	ns
t _{PZH}	Output Enable Time x _{OE} to x _{Qx}	1	6.2	—	6	1	4.9	ns
t _{PLZ}	Output Disable Time x _{OE} to x _{Qx}	1.1	5.3	—	4.3	1.3	4.1	ns
t _{SU}	Set-up Time, data before LE↓	0.9	—	0.7	—	1.1	—	ns
t _H	Hold Time, data after LE↓	1.2	—	1.5	—	1.1	—	ns
t _W	Pulse Duration, x _{LE} HIGH	3.3	—	3.3	—	3.3	—	ns
t _{sk(0)}	Output Skew ⁽²⁾	—	—	—	—	—	500	ps

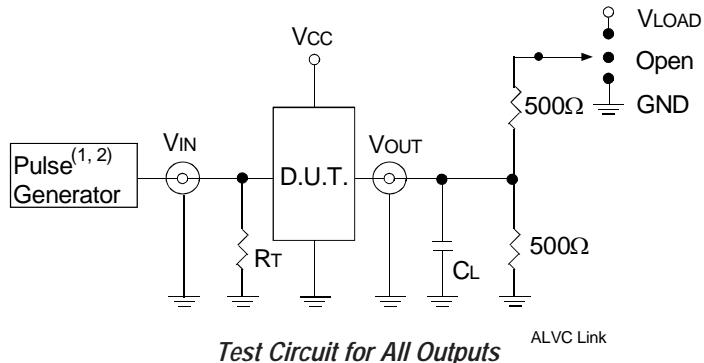
NOTES:

1. See TEST CIRCUITS AND WAVEFORMS. TA = - 40°C to + 85°C.
2. Skew between any two outputs of the same package and switching in the same direction.

TEST CIRCUITS AND WAVEFORMS

TEST CONDITIONS

Symbol	$V_{CC}^{(1)} = 3.3V \pm 0.3V$	$V_{CC}^{(1)} = 2.7V$	$V_{CC}^{(2)} = 2.5V \pm 0.2V$	Unit
V_{LOAD}	6	6	$2 \times V_{CC}$	V
V_{IH}	2.7	2.7	V_{CC}	V
V_T	1.5	1.5	$V_{CC} / 2$	V
V_{LZ}	300	300	150	mV
V_{HZ}	300	300	150	mV
C_L	50	50	30	pF



DEFINITIONS:

C_L = Load capacitance: includes jig and probe capacitance.

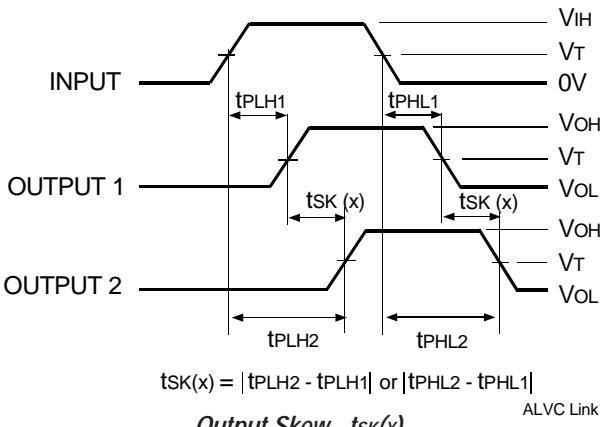
R_T = Termination resistance: should be equal to Z_{OUT} of the Pulse Generator.

NOTES:

1. Pulse Generator for All Pulses: Rate $\leq 1.0\text{MHz}$; $t_f \leq 2.5\text{ns}$; $t_r \leq 2.5\text{ns}$.
2. Pulse Generator for All Pulses: Rate $\leq 1.0\text{MHz}$; $t_f \leq 2\text{ns}$; $t_r \leq 2\text{ns}$.

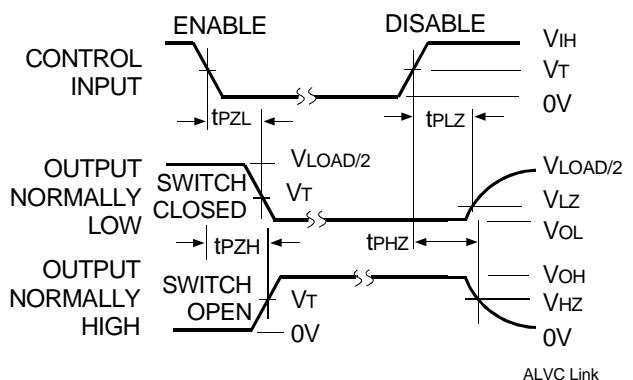
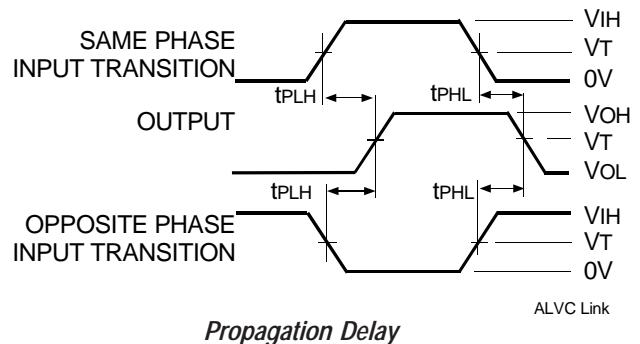
SWITCH POSITION

Test	Switch
Open Drain	
Disable Low	V_{LOAD}
Enable Low	
Disable High	GND
All Other Tests	Open



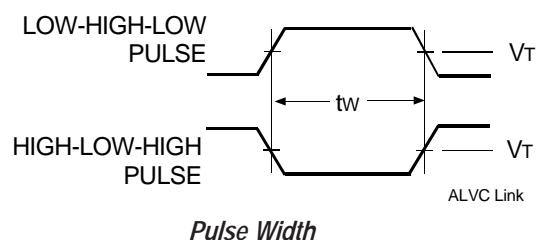
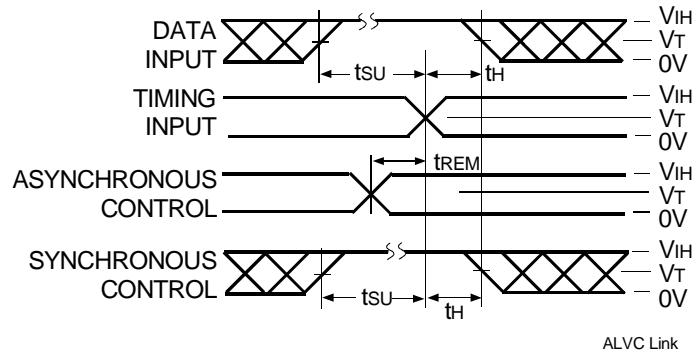
NOTES:

1. For $t_{SK}(o)$ OUTPUT1 and OUTPUT2 are any two outputs.
2. For $t_{SK}(b)$ OUTPUT1 and OUTPUT2 are in the same bank.



NOTE:

1. Diagram shown for input Control Enable-LOW and input Control Disable-HIGH.



ORDERING INFORMATION

IDT	XX	ALVC	X	XXX	XXX	XX
Temp. Range	Bus-Hold	Family		Device Type	Package	
					PV	Shrink Small Outline Package
					PA	Thin Shrink Small Outline Package
					PF	Thin Very Small Outline Package
				841		20-Bit Bus-Interface D-Type Latch with 3-State Outputs
				16		Double-Density, $\pm 24\text{mA}$
				H		Bus-Hold
				74		-40°C to +85°C



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